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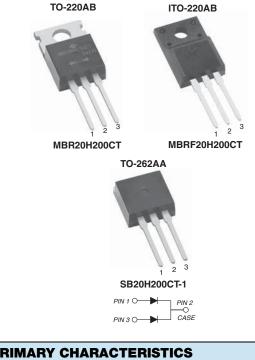
ISHA

MBR20H200CT, MBRF20H200CT, SB20H200CT-1

Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

Low Leakage Current 5.0 µA



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 10 A				
V _{RRM}	200 V				
I _{FSM}	290 A				
V _F	0.75 V				
T _J max.	175 °C				
Package	TO-220AB, ITO-220AB, TO-262AA				
Diode variations	Common cathode				

FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- High frequency operation
- Solder dip 275 °C max., 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	VALUE	UNIT		
Maximum repetitive peak reverse voltage		V _{RRM}	200	V		
Working peak reverse voltage		V _{RWM}	200	V		
Maximum DC blocking voltage		V _{DC}	200	V		
Maximum average forward restified surrent	otal device	1	20	^		
Maximum average forward rectified current	oer diode	I _{F(AV)}	10	A		
Peak forward surge current 8.3 ms single half sine-wave super on rated load per diode	rimposed	I _{FSM}	290	А		
Peak repetitive reverse current per diode at $t_p = 2 \ \mu s$, 1 kHz		I _{RRM}	1.0	А		
Peak non-repetitive reverse surge energy per diode (8/20 µs w	aveform)	E _{RSM}	20	mJ		
Non-repetitive avalanche energy per diode at 25 °C, I_{AS} = 2.0 Å	, L = 10 mH	E _{AS}	20	mJ		
Electrostatic discharge capacitor voltage human body model air discharge: C = 100 pF, R = 1.5 k Ω		V _C	25	kV		
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs		
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +175	°C			
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min		V _{AC}	1500	V		

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COMPLIANT



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ELECTRICAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode	I _F = 10 A	T _C = 25 °C		0.81	0.88		
	I _F = 10 A	T _C = 125 °C	V _E ⁽¹⁾	0.65	0.75	v	
	I _F = 20 A	T _C = 25 °C	VF ()	0.87	0.97	v	
	I _F = 20 A	T _C = 125 °C		0.74	0.85		
Maximum reverse current per diode		T _J = 25 °C	L (1)	I _B ⁽¹⁾ 5.0		μA	
at working peak reverse voltage		T _J = 125 °C	IR (1)	1.0		mA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	250		pF	

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	SB	UNIT	
Typical thermal resistance per diode	$R_{ extsf{ heta}JC}$	2.0	4.0	2.0	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR20H200CT-E3/45	2.06	45	50/tube	Tube	
ITO-220AB	MBRF20H200CT-E3/45	2.20	45	50/tube	Tube	
TO-262AA	SB20H200CT-1E3/45	1.58	45	50/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

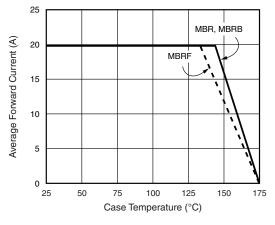


Fig. 1 - Forward Derating Curve (Total)

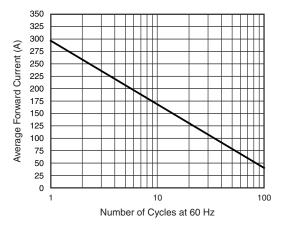


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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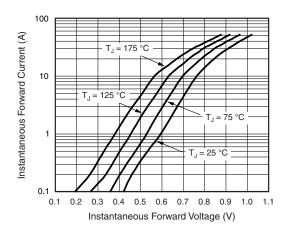


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

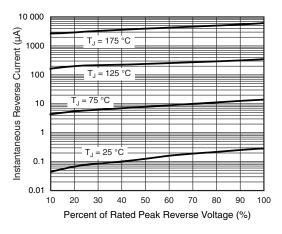


Fig. 4 - Typical Reverse Characteristics Per Diode

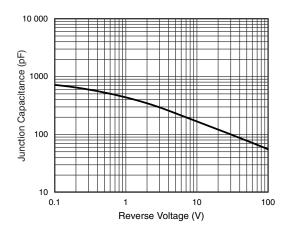


Fig. 5 - Typical Junction Capacitance Per Diode

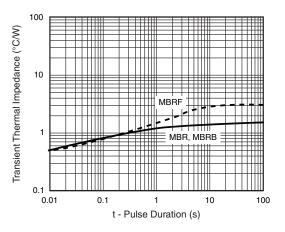


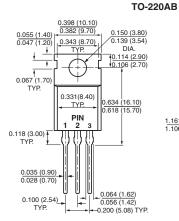
Fig. 6 - Typical Transient Thermal Impedance Per Diode



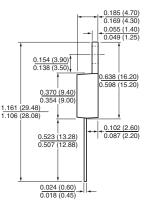
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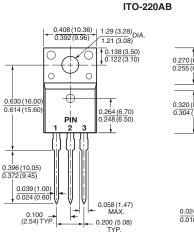
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

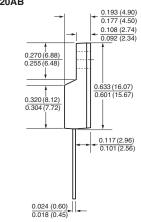
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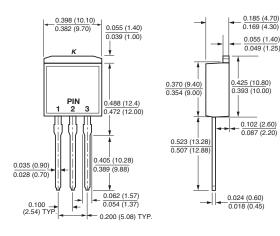
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TO-262AA



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